INTEGRATED CIRCUITS

DATA SHEET

74F08Quad two-input AND gate

Product specification

1995 Apr 19

IC15 Data Handbook

Philips Semiconductors





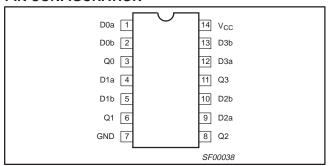
Quad 2-input AND gate

74F08

• 74F08 Available for industrial range (-40°C to +85°C)

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F08	4.1ns	7.1mA

PIN CONFIGURATION



ORDERING INFORMATION

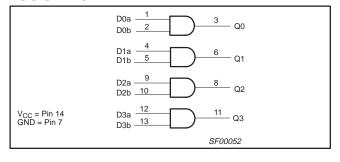
DESCRIPTION	COMMERCIAL RANGE $V_{CC} = 5.0V \pm 10\%, T_{amb} = 0^{\circ}\text{C to } +70^{\circ}\text{C}$	INDUSTRIAL RANGE V_{CC} = 5.0V $\pm 10\%$, T_{amb} = -40° C to $+85^{\circ}$ C	PKG DWG#
14-pin plastic DIP	N74F08N	I74F08N	SOT27-1
14-pin plastic SO	N74F08D	I74F08D	SOT108-1

INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
Dna, Dnb	Data inputs	1.0/1.0	20μA/0.6mA
Qn	Data output	50/33	1.0mA/20mA

NOTE: One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

LOGIC DIAGRAM



FUNCTION TABLE

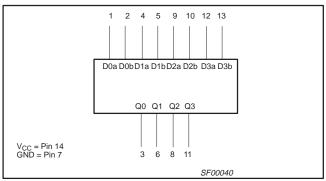
INP	UTS	OUTPUT
Dna	Dnb	Qn
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

NOTES:

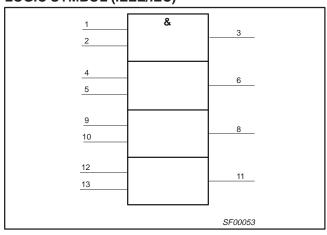
H = High voltage level

L = Low voltage level

LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



Quad 2-input AND gate

74F08

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT					
V _{CC}	Supply voltage		-0.5 to +7.0	V					
V _{IN}	Input voltage	put voltage							
I _{IN}	Input current	put current							
V _{OUT}	Voltage applied to output in High output state		–0.5 to V _{CC}	V					
I _{OUT}	Current applied to output in Low output state		40	mA					
_		Commercial range	0 to +70	°C					
l amb	Operating free-air temperature range	-40 to +85	°C						
T _{stg}	Storage temperature range	-	-65 to +150	°C					

RECOMMENDED OPERATING CONDITIONS

CVMDOL	PARAMETER			LIMITS		LINUT		
SYMBOL	PARAMETER	MIN	NOM	MAX	UNIT			
V _{CC}	Supply voltage	upply voltage						
V _{Ih}	High-level input voltage	2.0			V			
V _{IL}	Low-level input voltage				0.8	V		
I _{IK}	Input clamp current				-18	mA		
I _{OH}	High-level output current				-1	mA		
I _{OL}	Low-level output current				20	mA		
т.	Operating free-air temperature range	Commercial range	0		+70	°C		
lamb	Operating nee-all temperature range	Industrial range	-40		+85	°C		

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

OVMDOL	DADAMETED		TEGT CONDITIO	NO1		LIMITS		
SYMBOL	PARAMETER		TEST CONDITIO	MIN	TYP ²	MAX	UNIT	
V	High-level output voltage		$V_{CC} = MIN, V_{IL} = MAX$	±10%V _{CC}	2.5			V
V _{OH}	Trigit-level output voltage		V _{IH} = MIN, I _{OH} = MAX	±5%V _{CC}	2.7	3.4		V
V	Low lovel output voltage		$V_{CC} = MIN, V_{IL} = MAX$	±10%V _{CC}		0.30	0.50	V
V _{OL}	Low-level output voltage		$V_{IH} = MIN, I_{OI} = MAX$		0.30	0.50	V	
V _{IK}	Input clamp voltage		$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.2	V	
I _I	Input current at maximum voltage	input	$V_{CC} = MAX, V_I = 7.0V$			100	μΑ	
I _{IH}	High-level input current		$V_{CC} = MAX, V_I = 2.7V$				20	μΑ
I _{IL}	Low-level input current		$V_{CC} = MAX, V_I = 0.5V$				-0.6	mA
I _{OS}	Short-circuit output current ³		V _{CC} = MAX		-60		-150	mA
la a	Cupply ourrant (total)	I _{CCH}	V _{CC} = MAX	$V_{IN} = 4.5V$		5.5	8.3	mA
Icc	Supply current (total) I _{CCL}		$V_{CC} = MAX$	V _{IN} = GND		8.6	12.9	mA

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

2. All typical values are at V_{CC} = 5V, T_{amb} = 25°C.

1995 Apr 19 3

^{3.} Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

Philips Semiconductors Product specification

Quad 2-input AND gate

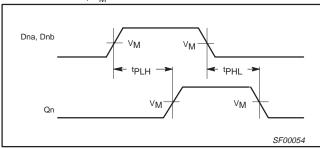
74F08

AC ELECTRICAL CHARACTERISTICS

SYMBOL			LIMITS									
SYMBOL	PARAMETER	TEST CONDITION	$T_{amb} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50pF,$ $R_{L} = 500\Omega$			V _{CC} = +5. C _L =	C to +70°C 0V ± 10% 50pF, 500Ω	T _{amb} = -40° V _{CC} = +5. C _L = 8 R _L =	UNIT			
			MIN	TYP	MAX	MIN	MAX	MIN	MAX			
t _{PLH} t _{PHL}	Propagation delay Dna, Dnb to Qn	Waveform 1	3.0 2.5	4.2 4.0	5.6 5.3	3.0 2.5	6.6 6.3	2.5 2.5	6.6 6.3	ns		

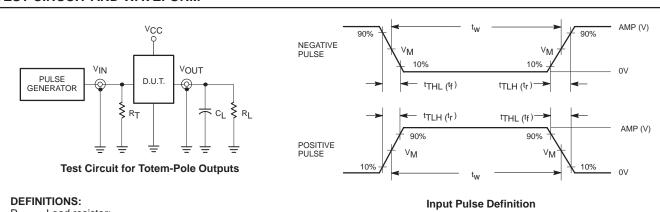
AC WAVEFORMS

For all waveforms, $V_M = 1.5V$.



Waveform 1. Propagation Delay for Non-Inverting Outputs

TEST CIRCUIT AND WAVEFORM



R_L = Load resistor;

see AC ELECTRICAL CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC ELECTRICAL CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

family	INP	UT PU	LSE REQU	REMEN	TS	
lallilly	amplitude	V_{M}	rep. rate	t _w	t _{TLH}	t _{THL}
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns

SF00006

1995 Apr 19

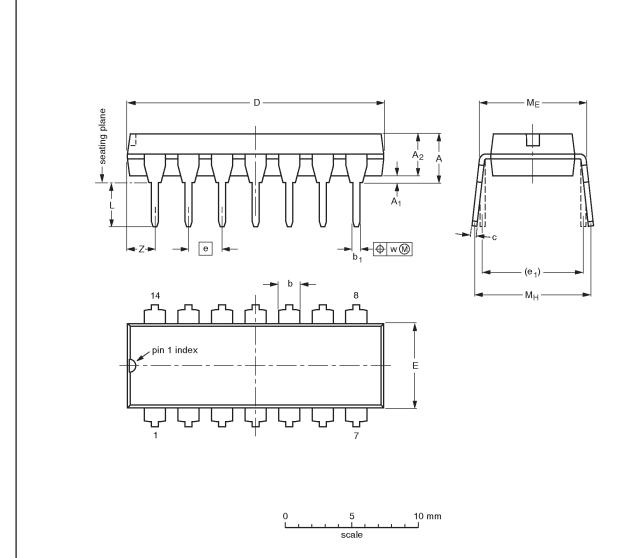
Philips Semiconductors Product specification

Quad 2-input AND gate

74F08

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	ı
SOT27-1	050G04	MO-001AA			92-11-17 95-03-11	

1995 Apr 19 5

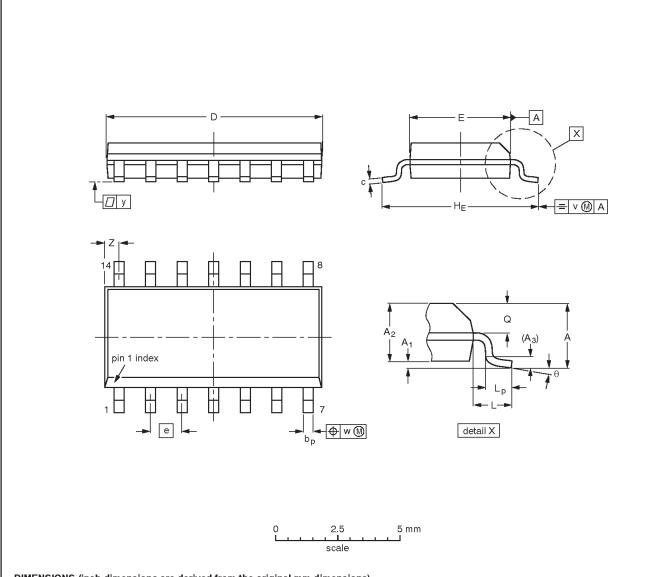
Philips Semiconductors Product specification

Quad 2-input AND gate

74F08

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES		EUROPEAN PROJECTION	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ			ISSUE DATE
SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22

1995 Apr 19 6 Philips Semiconductors Product specification

Quad 2-input AND gate

74F08

NOTES

1995 Apr 19 7

Quad 2-input AND gate

74F08

Data sheet status

Data sheet status	Product status	Definition [1]	
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.	
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.	
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product	

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

print code Date of release: 10-98

Document order number: 9397-750-05055

Let's make things better.

Philips Semiconductors



